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December 2001

FAIRCHILD SEMICONDUCTOR®

FDC6318P

Dual P-Channel 1.8V PowerTrench[®] Specified MOSFET

General Description

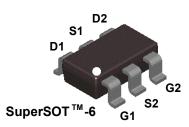
These P-Channel 1.8V specified MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain low gate charge for superior switching performance.

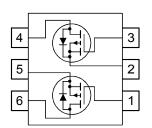
Applications

- Power management
- Load switch

Features

- -2.5 A, -12 V. $R_{DS(ON)} = 90 \text{ m}\Omega \textcircled{0} V_{GS} = -4.5 \text{ V}$ $R_{DS(ON)} = 125 \text{ m}\Omega \textcircled{0} V_{GS} = -2.5 \text{ V}$ $R_{DS(ON)} = 200 \text{ m}\Omega \textcircled{0} V_{GS} = -1.8 \text{ V}$
- + High performance trench technology for extremely low $\rm R_{\rm DS(ON)}$
- SuperSOTTM-6 package: small footprint (72% smaller than standard SO-8); low profile (1mm thick)





Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-12	V
V _{GSS}	Gate-Source Voltage		±8	V
ID	Drain Current – Continuous	(Note 1a)	-2.5	A
	- Pulsed		-7	
P _D	Power Dissipation for Single Operation	(Note 1a)	0.96	W
		(Note 1b)	0.9	
		(Note 1c)	0.7	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		–55 to +150	°C

Thermal Characteristics

$R_{ ext{ heta}JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	130	°C/W
R _{eJC}	Thermal Resistance, Junction-to-Case	(Note 1)	60	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
.318	FDC6318P	13"	12mm	3000 units
			•	

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Electrical Characteristics $T_{A} = 25^{\circ}C$ unless otherwise noted Symbol Min Parameter **Test Conditions** Тур Max Units **Off Characteristics** Drain-Source Breakdown Voltage -12 V $V_{GS} = 0 V$, $I_{\rm D} = -250 \ \mu A$ Breakdown Voltage Temperature -2.9 mV/°C ΔBV_{DSS} $I_D = -250 \ \mu A$, Referenced to $25^{\circ}C$ Coefficient Zero Gate Voltage Drain Current $V_{DS} = -10 V$, V_{GS} = 0 V -1 μΑ Gate-Body Leakage, Forward $V_{GS} = 8 V$, $V_{DS} = 0 V$ 100 nA $V_{GS} = -8 V.$ $V_{DS} = 0 V$ -100 Gate-Body Leakage, Reverse nA On Characteristics (Note 2) Gate Threshold Voltage $V_{DS} = V_{GS}$, I_D = -250 μA -0.4 -0.7 -1.5 V Gate Threshold Voltage I_D = -250 μ A, Referenced to 25°C mV/°C $\Delta V_{GS(th)}$ 2.3 **Temperature Coefficient** Static Drain-Source $V_{GS} = -4.5 V$, $I_D = -2.5 A$ 69 90 mΩ $V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -2 \text{ A}$ **On-Resistance** 93 125 $V_{GS} = -1.8 \text{ V}, \text{ I}_{D} = -1.6 \text{ A}$ 135 200 V_{GS}= -4.5 V, I_D = -2.5A, T_J=125°C 85 120 $V_{GS} = -4.5 V$, $V_{DS} = -5 V$ **On-State Drain Current** -6 А Forward Transconductance $V_{DS} = -5 V$, $I_{D} = -2.5 \text{ A}$ 8 S **Dynamic Characteristics** 455 Input Capacitance рF $V_{DS} = -6 V$, $V_{GS} = 0 V$, **Output Capacitance** f = 1.0 MHz 194 pF **Reverse Transfer Capacitance** 134 pF Switching Characteristics (Note 2) Turn-On Delay Time 9 18 $V_{DD} = -6 V.$ $I_{\rm D} = -1 \, {\rm A}$. ns $V_{GS} = -4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$ 25 Turn-On Rise Time 14 ns Turn-Off Delay Time 21 34 ns Turn–Off Fall Time 17 31 ns **Total Gate Charge** $V_{DS} = -6 V$, $I_{\rm D} = -2.5 \, {\rm A},$ 5.4 8 nC $V_{GS} = -4.5 V$ Gate-Source Charge nC 1.1 Gate-Drain Charge 1.3 nC **Drain–Source Diode Characteristics and Maximum Ratings** Maximum Continuous Drain-Source Diode Forward Current -0.8 A Drain-Source Diode Forward $V_{GS} = 0 V$, $I_{\rm S} = -0.8 \, \text{A}$ (Note 2) -0.7 -1.2V Voltage

Notes:

Is

 V_{SD}

BV_{DSS}

 ΔT_{J}

IDSS

IGSSF

IGSSR

V_{GS(th)}

 $\Delta T_{\rm J}$ $R_{\text{DS(on)}}$

I_{D(on)}

g_{FS}

C_{iss}

Coss

 C_{rss}

t_{d(on)}

 $t_{d(off)}$

tr

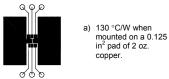
 $t_{\rm f}$

 Q_{g}

Qgs

 Q_{gd}

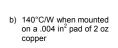
1. R_{8JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{e.IC} is guaranteed by design while R_{eCA} is determined by the user's board design.



2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

Scale 1:1 on letter size paper



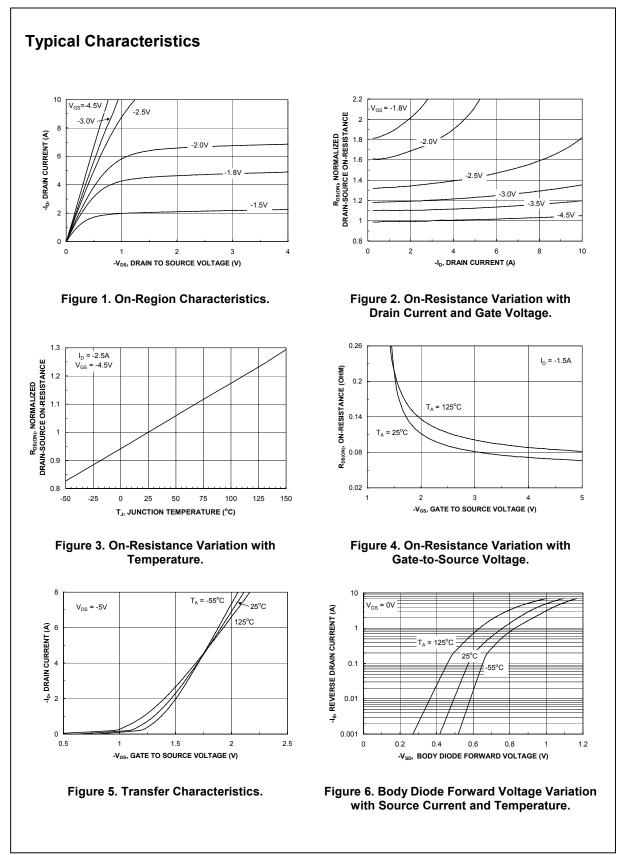




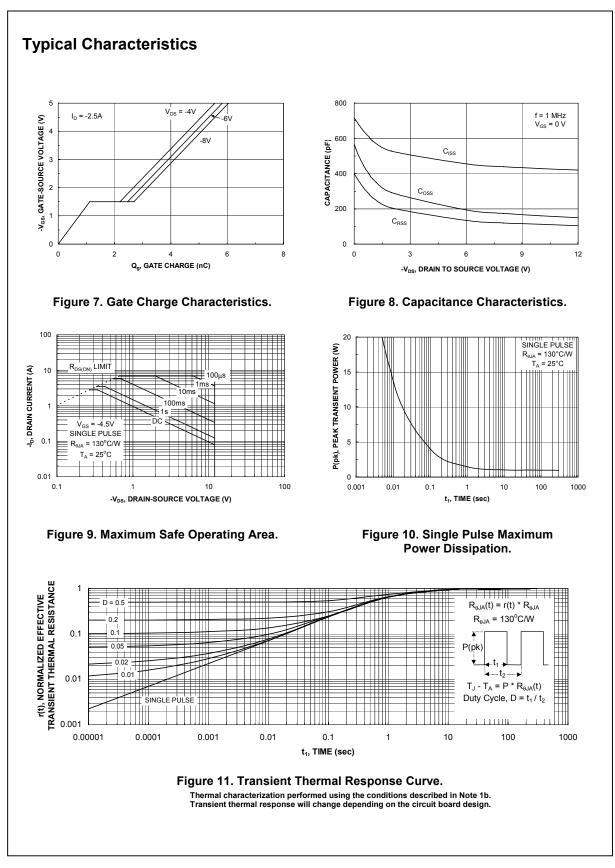
c) 180°C/W when mounted on a minimum pad.

FDC6318P Rev D (W)

FDC6318P



FDC6318P



FDC6318P

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